

Silicon PIN Photodiode

VEMD2520X01



16758-11

VEMD2500X01



DESCRIPTION

VEMD2500X01 and VEMD2520X01 are high speed and high sensitive PIN photodiodes in a clear epoxy, miniature surface mount package (SMD) with dome lens. The photo sensitive area of the chip is 0.23 mm².

FEATURES

- Package type: surface mount
- Package form: GW, RGW
- Dimensions (L x W x H in mm): 2.3 x 2.3 x 2.8
- AEC-Q101 qualified
- High radiant sensitivity
- Suitable for visible and near infrared radiation
- Fast response times
- Angle of half sensitivity: $\phi = \pm 15^\circ$
- Package matched with IR emitter series VSMB2000X01
- Floor life: 4 weeks, MSL 2a, acc. J-STD-020
- Lead (Pb)-free reflow soldering
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC

AUTOMOTIVE GRADE



RoHS
COMPLIANT
GREEN
*(S-2008)***

Note

** Please see document "Vishay Material Category Policy":
www.vishay.com/doc?99902

APPLICATIONS

- High speed photo detector

PRODUCT SUMMARY

COMPONENT	I _{ra} (μ A)	ϕ (deg)	$\lambda_{0.1}$ (nm)
VEMD2500X01	12	± 15	350 to 1120
VEMD2520X01	12	± 15	350 to 1120

Note

- Test conditions see table "Basic Characteristics"

ORDERING INFORMATION

ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM
VEMD2500X01	Tape and reel	MOQ: 6000 pcs, 6000 pcs/reel	Reverse gullwing
VEMD2520X01	Tape and reel	MOQ: 6000 pcs, 6000 pcs/reel	Gullwing

Note

- MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS ($T_{amb} = 25^\circ C$, unless otherwise specified)

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage		V _R	60	V
Power dissipation	$T_{amb} \leq 25^\circ C$	P _V	215	mW
Junction temperature		T _j	100	°C
Operating temperature range		T _{amb}	- 40 to + 100	°C
Storage temperature range		T _{stg}	- 40 to + 100	°C
Soldering temperature	Acc. reflow solder profile fig. 7	T _{sd}	260	°C
Thermal resistance junction/ambient	Acc. J-STD-051	R _{thJA}	250	K/W

BASIC CHARACTERISTICS ($T_{amb} = 25^\circ\text{C}$, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	$I_F = 50 \text{ mA}$	V_F		1		V
Breakdown voltage	$I_R = 100 \mu\text{A}, E = 0$	$V_{(BR)}$	32			V
Reverse dark current	$V_R = 10 \text{ V}, E = 0$	I_{ro}		1	10	nA
Diode capacitance	$V_R = 0 \text{ V}, f = 1 \text{ MHz}, E = 0$	C_D		4		pF
	$V_R = 5 \text{ V}, f = 1 \text{ MHz}, E = 0$	C_D		1.3		pF
Open circuit voltage	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}$	V_o		350		mV
Temperature coefficient of V_o	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}$	TK_{Vo}		- 2.6		mV/K
Short circuit current	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}$	I_k		11		µA
Temperature coefficient of I_k	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}$	TK_{Ik}		0.1		%/K
Reverse light current	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}, V_R = 5 \text{ V}$	I_{ra}	8.5	12	17	µA
Angle of half sensitivity		ϕ		± 15		deg
Wavelength of peak sensitivity		λ_p		900		nm
Range of spectral bandwidth		$\lambda_{0.1}$		350 to 1120		nm
Rise time	$V_R = 10 \text{ V}, R_L = 1 \text{ k}\Omega, \lambda = 820 \text{ nm}$	t_r		100		ns
Fall time	$V_R = 10 \text{ V}, R_L = 1 \text{ k}\Omega, \lambda = 820 \text{ nm}$	t_f		100		ns

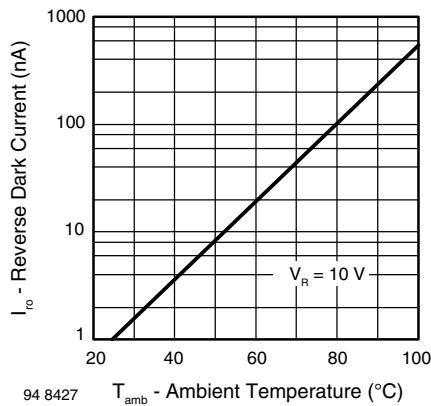
BASIC CHARACTERISTICS ($T_{amb} = 25^\circ\text{C}$, unless otherwise specified)


Fig. 1 - Reverse Dark Current vs. Ambient Temperature

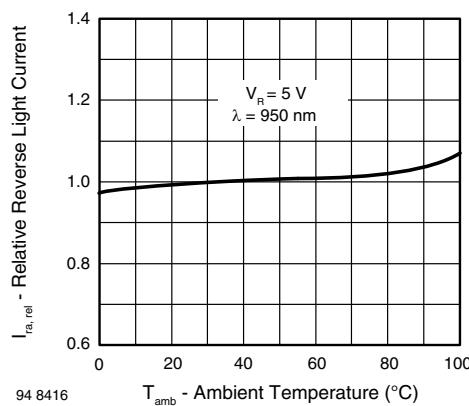


Fig. 2 - Relative Reverse Light Current vs. Ambient Temperature

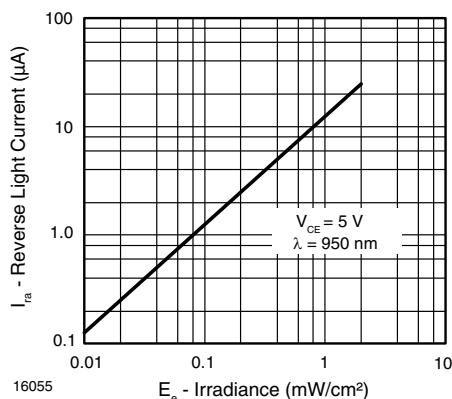


Fig. 3 - Reverse Light Current vs. Irradiance

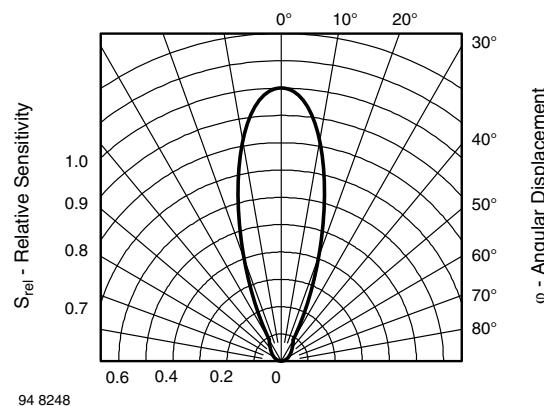


Fig. 6 - Relative Radiant Sensitivity vs. Angular Displacement

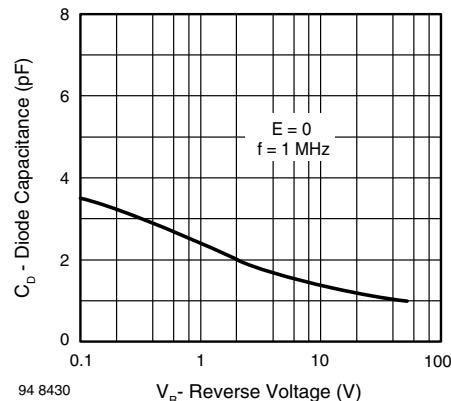


Fig. 4 - Diode Capacitance vs. Reverse Voltage

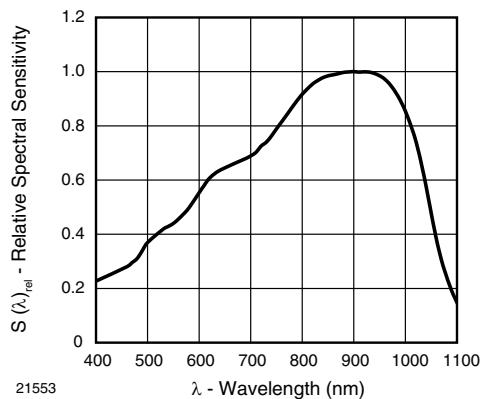


Fig. 5 - Relative Spectral Sensitivity vs. Wavelength

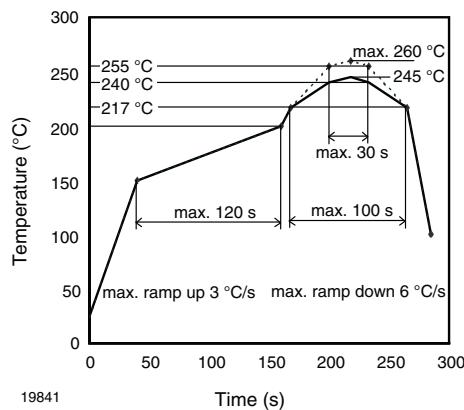
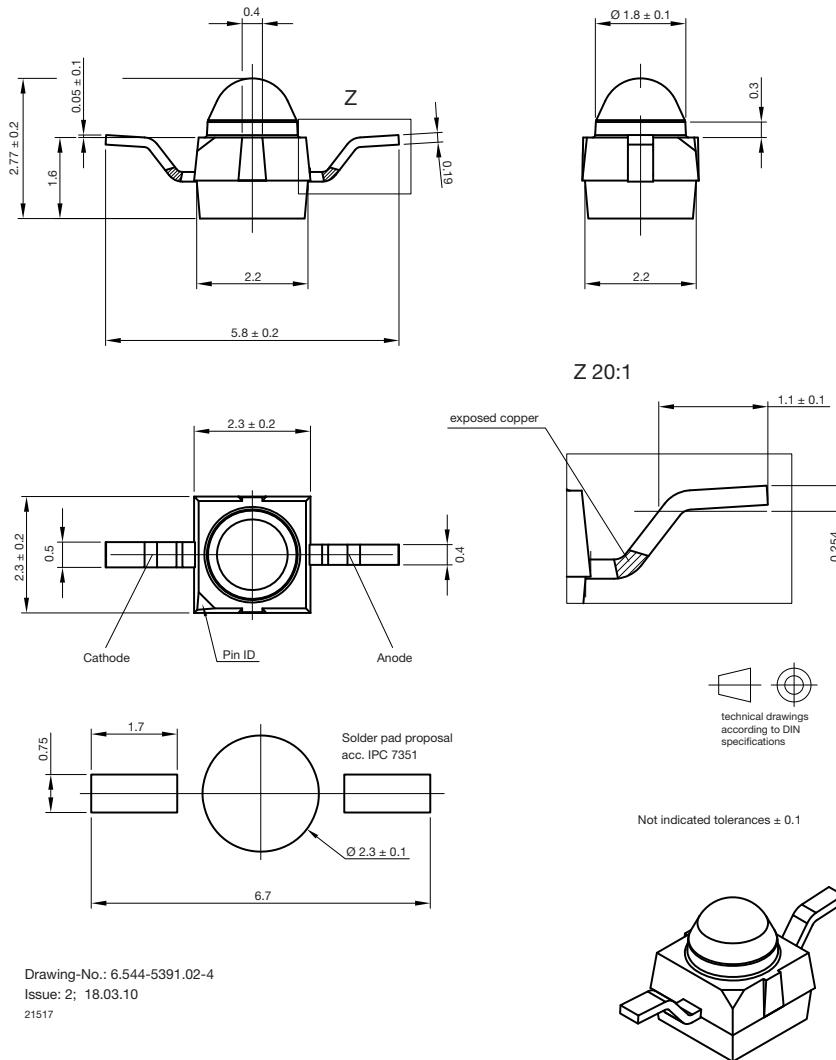
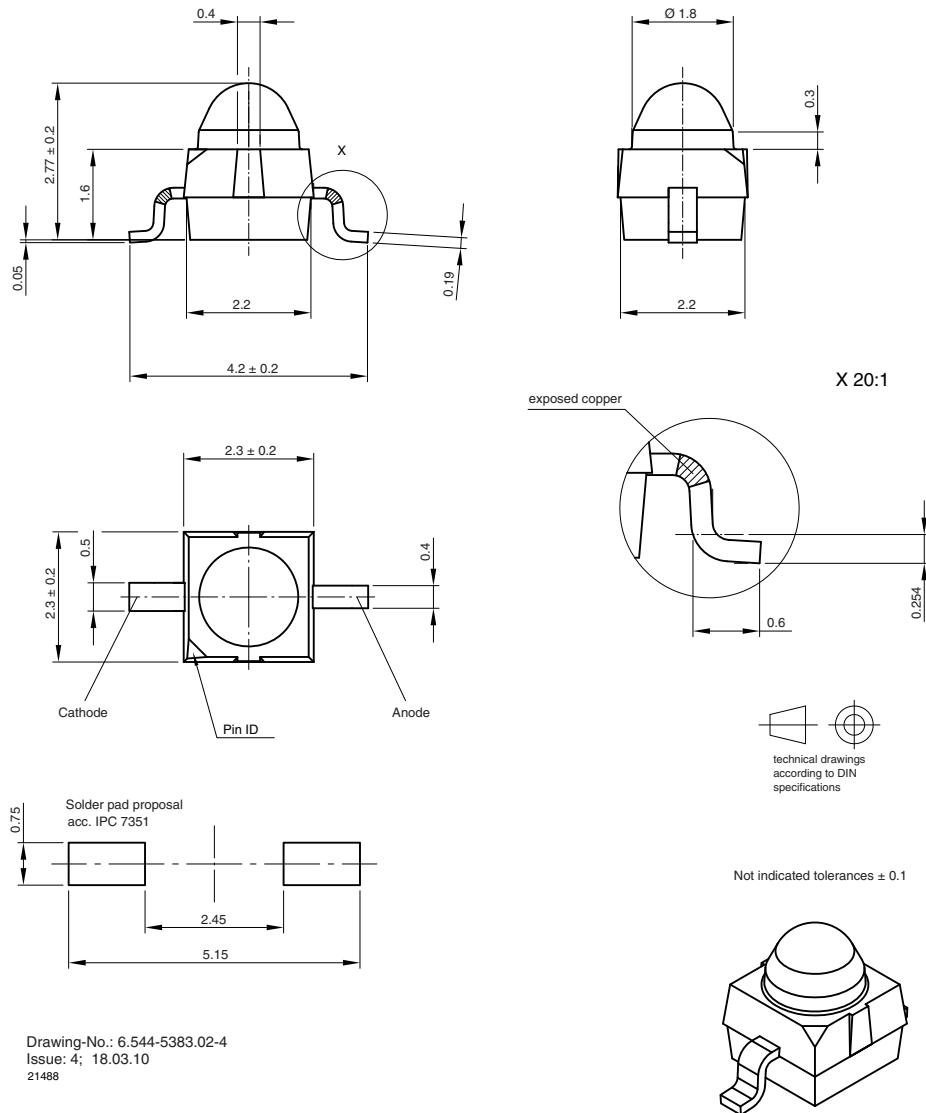
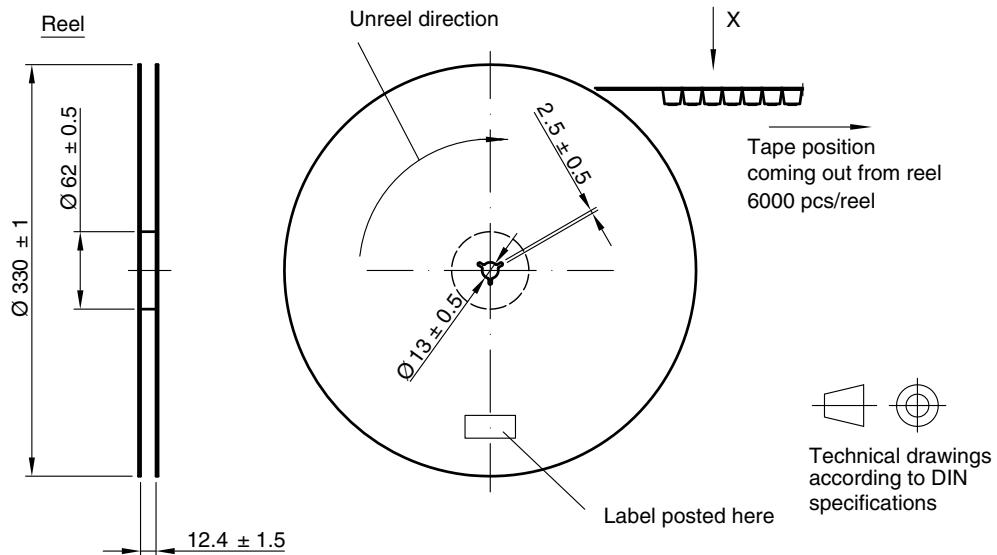
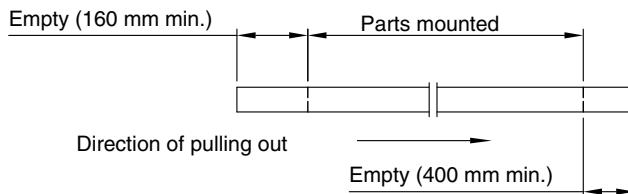
REFLOW SOLDER PROFILE


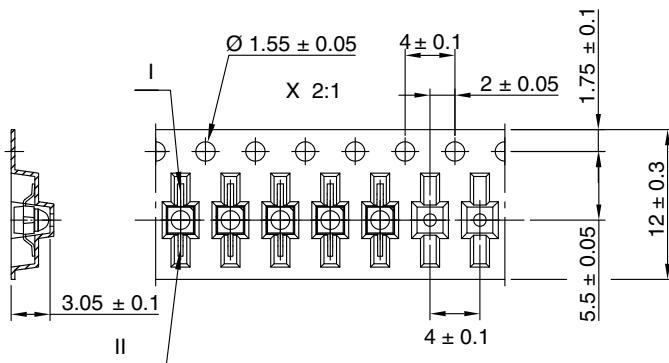
Fig. 7 - Lead (Pb)-free Reflow Solder Profile acc. J-STD-020D

PACKAGE DIMENSIONS in millimeters: **VEMD2500X01**


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TAPING AND REEL DIMENSIONS in millimeters: **VEMD2500X01**

Leader and trailer tape:

Terminal position in tape

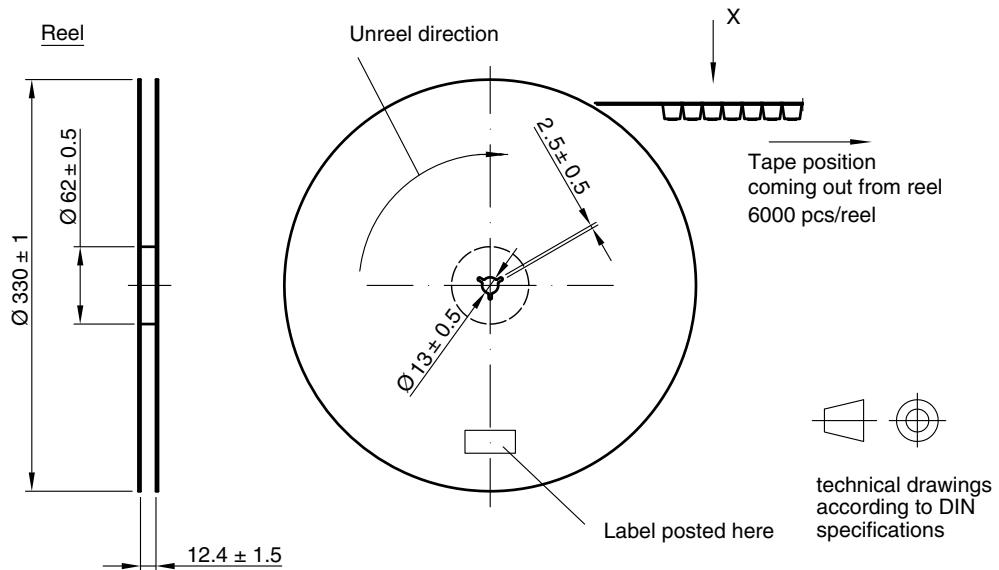
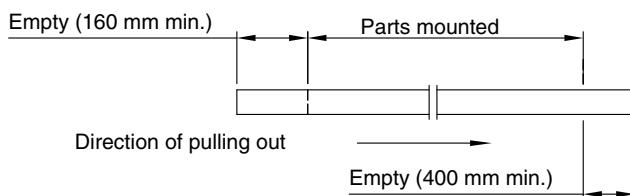
Device	Lead I	Lead II
VEMT2000		
VEMT2500	Collector	Emitter
VEMD2000		
VEMD2500	Cathode	Anode
VSMB2000		
VSMG2000		
VS MY2850RG	Anode	Cathode



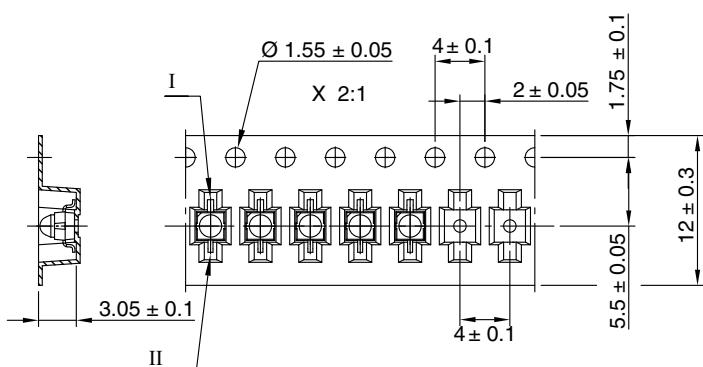
Drawing-No.: 9.800-5100.01-4

Issue: 2; 18.03.10

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TAPING AND REEL DIMENSIONS in millimeters: **VEMD2520X01**

Leader and trailer tape:

Terminal position in tape

Device	Lead I	Lead II
VEMT2020		
VEMT2520	Collector	Emitter
VSMB2020		
VSMG2020		
VEMD2020	Cathode	Anode
VEMD2520		
VSMY2850G	Anode	Cathode



Drawing-No.: 9.800-5091.01-4

Issue: 3; 18.03.10

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